NSN 5962-01-341-9681

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View Online at https://aerobasegroup.com/nsn/5962-01-341-9681

Overall Length:		
1.060 inches		
Overall Height:		
0.400 inches		
Body Length:		
1.060 inches		
Body Width:		
Between 0.220 inches a	nd 0.310 inches	
Body Height:		
Between 0.130 inches a	nd 0.185 inches	
Maximum Power Dissi	Dation Rating:	
1.1 watts		
Operating Tempurature	e Range:	
-55.0/+125.0 degrees ce	Isius	
Storage Tempurature F	ange:	
-65.0/+150.0 degrees ce	Isius	
Features Provided:		
Bipolar and high impeda	nce and w/clock and monolithic and programmed	
Inclosure Material:		
Ceramic		
Inclosure Configuration	n:	
Dual-in-line		
Output Logic Form:		
Transistor-transistor logi	c	
Input Circuit Pattern:		
16 input		
Case Outline Source A	nd Designator:	
D-8 mil-m-38510		
Current Rating Per Cha	aracteristic:	
180.00 milliamperes sup	oply	
Terminal Surface Treat	ment:	
Solder		
Product Name:		
And-or invert gate array		
Voltage Rating And Ty	pe Per Characteristic:	
-0.5 volts power source	and 12.0 volts power source	
Time Rating Per Chacter	eristic:	
50.00 nanoseconds pro	pagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level	
output		
Memory Device Type:		
Programmable		
Test Data Document:		
96906-mil-std-883 stand	ard (includes industry or association standards individual manufactureer standards, etc.)	

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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